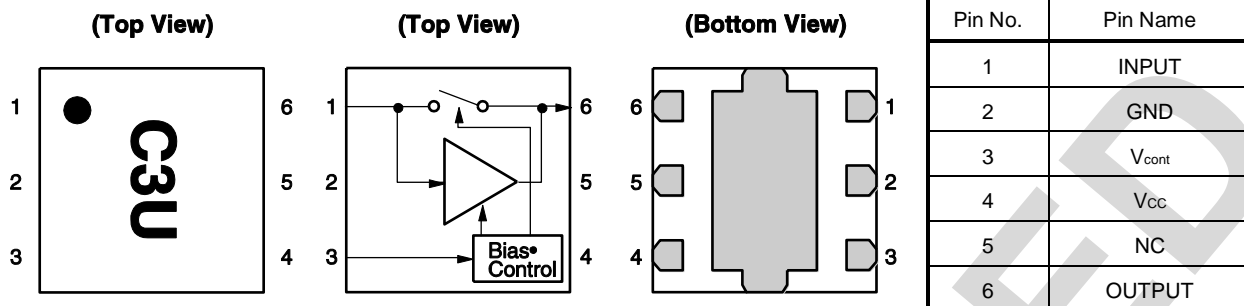


PIN CONNECTIONS AND INTERNAL BLOCK DIAGRAM



Remark Exposed pad : GND

TRUTH TABLE

V_{cont}	Gain	Mode
H	High	LNA-mode
L	Low	Bypass-mode

Remark "H" = V_{cont} (H), "L" = V_{cont} (L)

ABSOLUTE MAXIMUM RATINGS

Parameter	Symbol	Test Conditions	Ratings	Unit
Supply Voltage	V_{cc}	$T_A = +25^\circ\text{C}$	3.6	V
Mode Control Voltage	V_{cont}	$T_A = +25^\circ\text{C}$	3.6	V
Total Power Dissipation	P_{tot}		150	mW
Operating Ambient Temperature	T_A		-40 to +85	$^\circ\text{C}$
Storage Temperature	T_{stg}		-55 to +150	$^\circ\text{C}$
Input Power	P_{in}		+33	dBm

RECOMMENDED OPERATING RANGE

Parameter	Symbol	MIN.	TYP.	MAX.	Unit
Supply Voltage	V_{cc}	2.3	2.8	3.3	V
Mode Control Voltage (H)	V_{cont} (H)	1.0	—	V_{cc}	V
Mode Control Voltage (L)	V_{cont} (L)	0	—	0.5	V
Operating Frequency	f	50	—	1 800	MHz
Operating Ambient Temperature	T_A	-40	+25	+85	$^\circ\text{C}$
Input Power (LNA-mode)	P_{in}	—	—	+7	dBm
Input Power (Bypass-mode)	P_{in}	—	—	+15	dBm

ELECTRICAL CHARACTERISTICS 1 (DC Characteristics)(T_A = +25°C, V_{CC} = 2.8 V, unless otherwise specified)

Parameter	Symbol	Test Conditions	MIN.	TYP.	MAX.	Unit
Circuit Current 1	I _{cc1}	V _{cont} = 2.8 V, No Signal (LNA-mode)	3.8	5.0	6.5	mA
Circuit Current 2	I _{cc2}	V _{cont} = 0 V, No Signal (Bypass-mode)	–	–	1	μ A
Mode Control Current 1	I _{cont1}	V _{cont} = 2.8 V, No Signal (LNA-mode)	–	40	100	μ A
Mode Control Current 2	I _{cont2}	V _{cont} = 0 V, No Signal (Bypass-mode)	–	–	1	μ A

ELECTRICAL CHARACTERISTICS 2 (LNA-mode)(T_A = +25°C, V_{CC} = V_{cont} = 2.8 V, unless otherwise specified)

Parameter	Symbol	Test Conditions	MIN.	TYP.	MAX.	Unit
Power Gain 1	G _{P1}	f = 470 MHz, P _{in} = –30 dBm	13.0	15.0	17.0	dB
Power Gain 2	G _{P2}	f = 770 MHz, P _{in} = –30 dBm	11.5	13.5	15.5	dB
Noise Figure 1	NF1	f = 470 MHz, excluded PCB and connector losses Note	–	1.5	2.0	dB
Noise Figure 2	NF2	f = 770 MHz, excluded PCB and connector losses Note	–	1.5	2.0	dB
Input Return Loss 1	RL _{in1}	f = 470 MHz, P _{in} = –30 dBm	7	12	–	dB
Input Return Loss 2	RL _{in2}	f = 770 MHz, P _{in} = –30 dBm	7	10	–	dB
Output Return Loss 1	RL _{out1}	f = 470 MHz, P _{in} = –30 dBm	7	14	–	dB
Output Return Loss 2	RL _{out1}	f = 770 MHz, P _{in} = –30 dBm	7	11	–	dB
Input 3rd Order Intercept Point 1	IIP ₃₁	f ₁ = 470 MHz, f ₂ = 471 MHz, P _{in} = –30 dBm	–4.0	–1.0	–	dBm
Input 3rd Order Intercept Point 2	IIP ₃₂	f ₁ = 770 MHz, f ₂ = 771 MHz, P _{in} = –30 dBm	–1.0	+2.0	–	dBm

Note Input PCB and connector losses: 0.05 dB (at 470 MHz), 0.08 dB (at 770 MHz)

ELECTRICAL CHARACTERISTICS 3 (Bypass-mode)**(T_A = +25°C, V_{CC} = 2.8 V, unless otherwise specified)**

Parameter	Symbol	Test Conditions	MIN.	TYP.	MAX.	Unit
Insertion Loss 1	L _{ins1}	f = 470 MHz, P _{in} = -10 dBm, excluded PCB and connector losses Note	–	1.1	2	dB
Insertion Loss 2	L _{ins2}	f = 770 MHz, P _{in} = -10 dBm, excluded PCB and connector losses Note	–	1.3	2	dB
Input Return Loss 1	RL _{in1}	f = 470 MHz, P _{in} = -10 dBm	10	20	–	dB
Input Return Loss 2	RL _{in2}	f = 770 MHz, P _{in} = -10 dBm	10	17	–	dB
Output Return Loss 1	RL _{out1}	f = 470 MHz, P _{in} = -10 dBm	10	20	–	dB
Output Return Loss 2	RL _{out1}	f = 770 MHz, P _{in} = -10 dBm	10	17	–	dB
Input 3rd Order Intercept Point	IIP ₃	f ₁ = 770 MHz, f ₂ = 771 MHz, P _{in} = -2.5 dBm	+20	+30	–	dBm

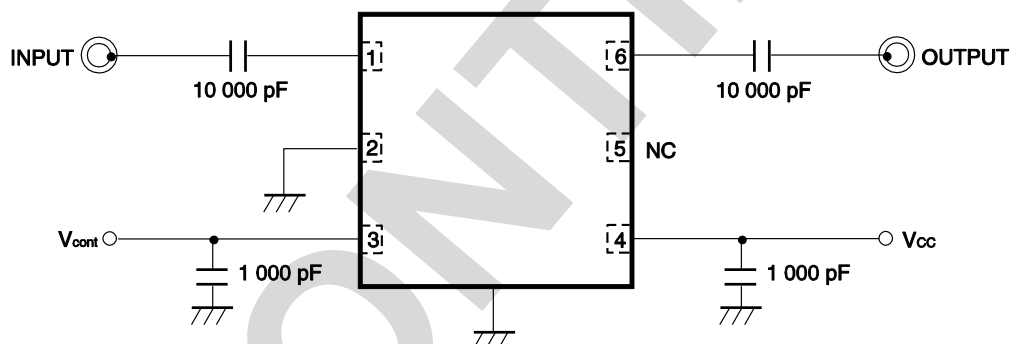
Note Input-output PCB and connector losses: 0.10 dB (at 470 MHz), 0.16 dB (at 770 MHz)

STANDARD CHARACTERISTICS FOR REFERENCE 1 (LNA-mode)**(T_A = +25°C, V_{CC} = V_{cont} = 2.8 V, unless otherwise specified)**

Parameter	Symbol	Test Conditions	Reference	Unit
Isolation 1	ISL1	f = 470 MHz, P _{in} = -30 dBm	20	dB
Isolation 2	ISL2	f = 770 MHz, P _{in} = -30 dBm	20	dB
Gain 1 dB Compression Output Power 1	P _{O (1 dB) 1}	f = 470 MHz	-5.5	dBm
Gain 1 dB Compression Output Power 2	P _{O (1 dB) 2}	f = 770 MHz	-5.0	dBm

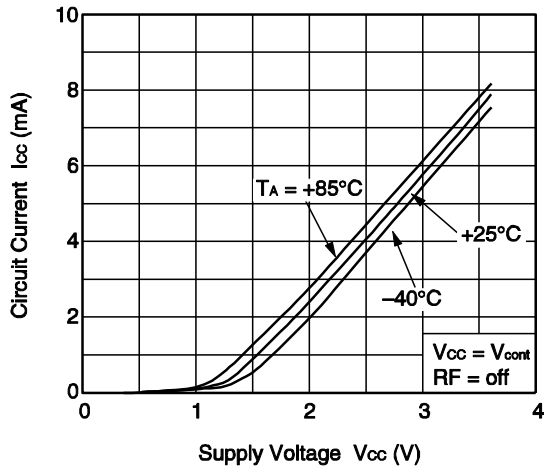
STANDARD CHARACTERISTICS FOR REFERENCE 2 (Bypass-mode)**(T_A = +25°C, V_{CC} = 2.8 V, V_{cont} = 0 V, unless otherwise specified)**

Parameter	Symbol	Test Conditions	Reference	Unit
Gain 1 dB Compression Output Power	P _{O (1 dB)}	f = 770 MHz	+8	dBm

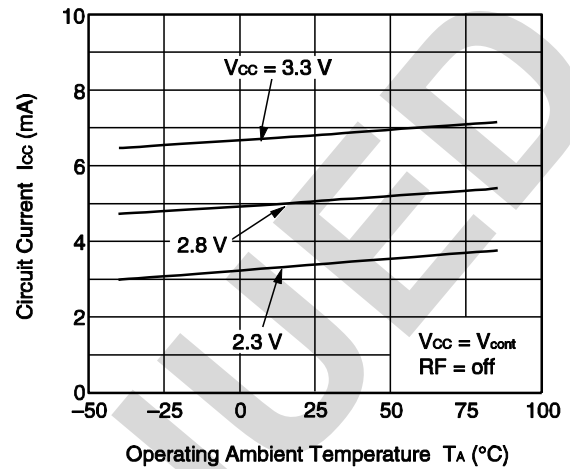
TEST CIRCUIT

TYPICAL CHARACTERISTICS 1 (DC Characteristics) ($T_A = +25^\circ\text{C}$, unless otherwise specified)

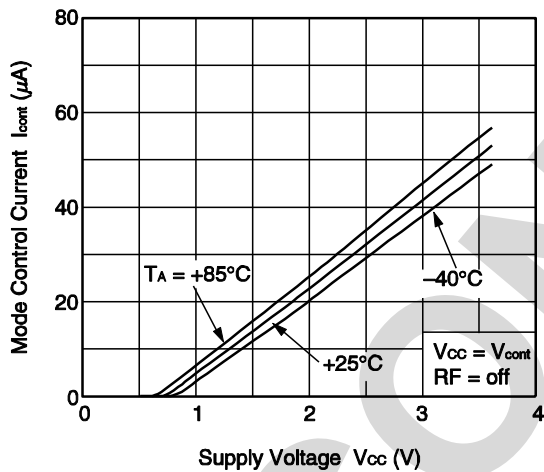
CIRCUIT CURRENT vs. SUPPLY VOLTAGE



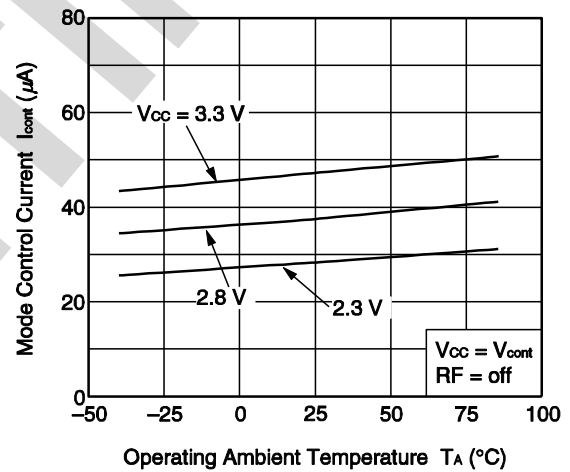
CIRCUIT CURRENT vs. OPERATING AMBIENT TEMPERATURE



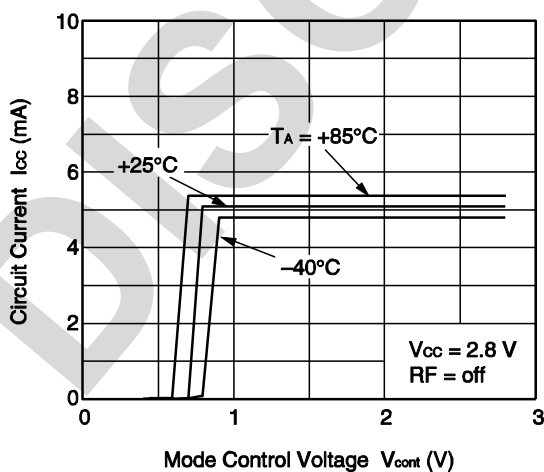
MODE CONTROL CURRENT vs. SUPPLY VOLTAGE



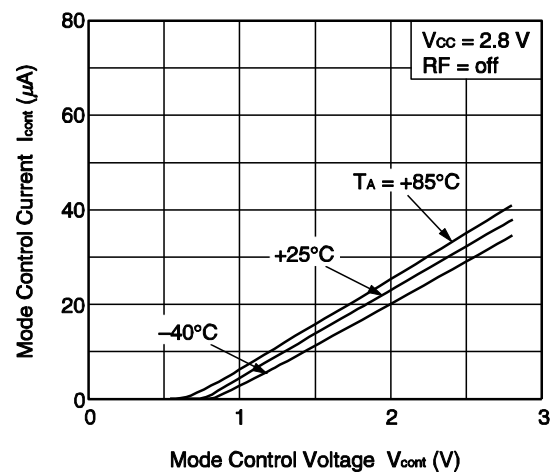
MODE CONTROL CURRENT vs. OPERATING AMBIENT TEMPERATURE



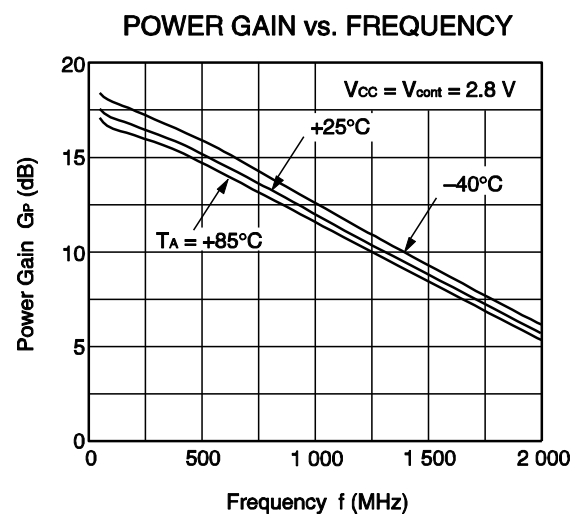
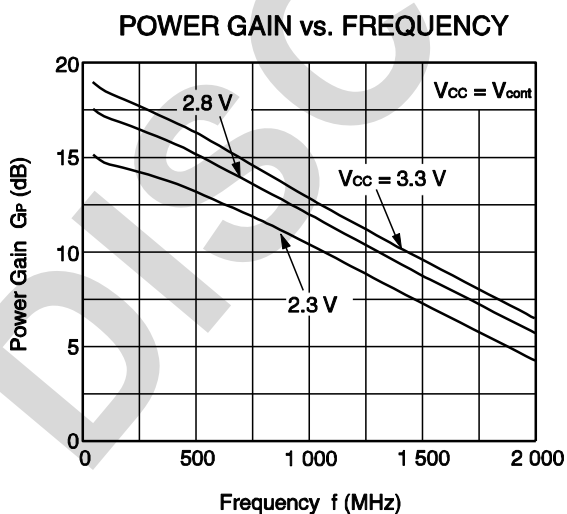
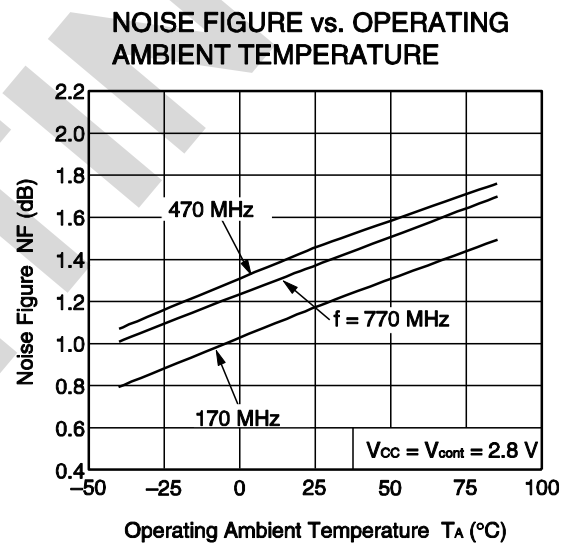
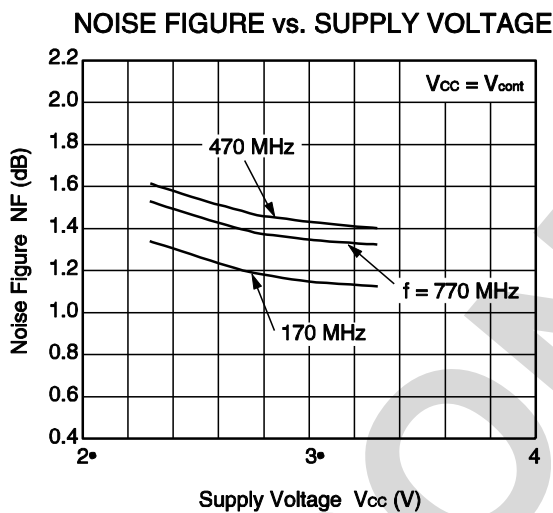
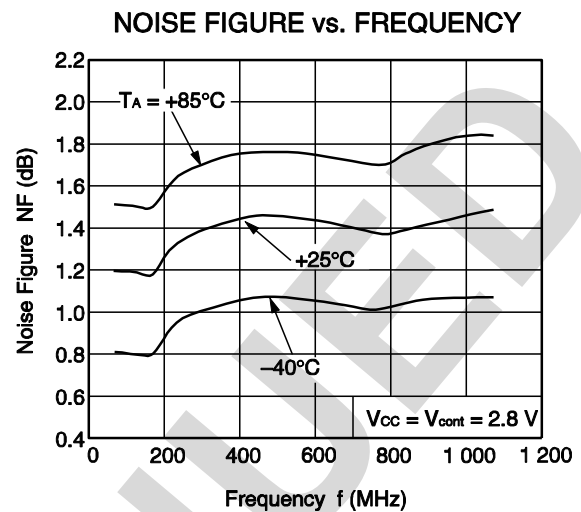
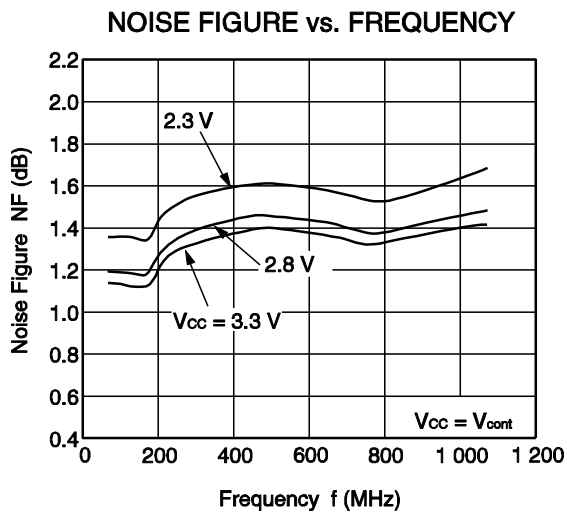
CIRCUIT CURRENT vs. MODE CONTROL VOLTAGE



MODE CONTROL CURRENT vs. MODE CONTROL VOLTAGE

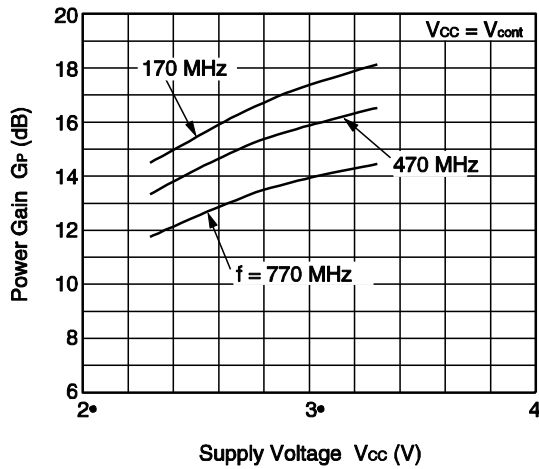


Remark The graphs indicate nominal characteristics.

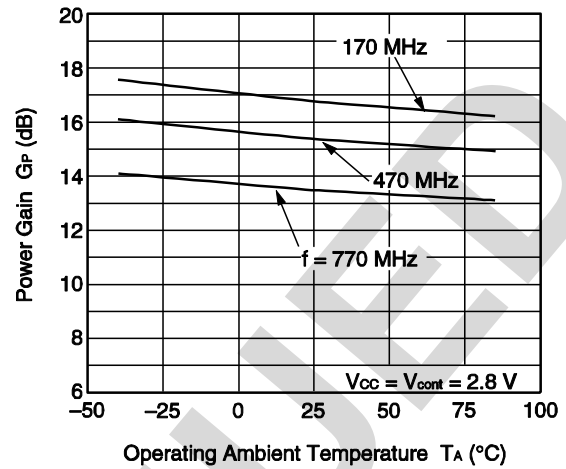
TYPICAL CHARACTERISTICS 2 (LNA-mode) ($T_A = +25^\circ\text{C}$, unless otherwise specified)

Remark The graphs indicate nominal characteristics.

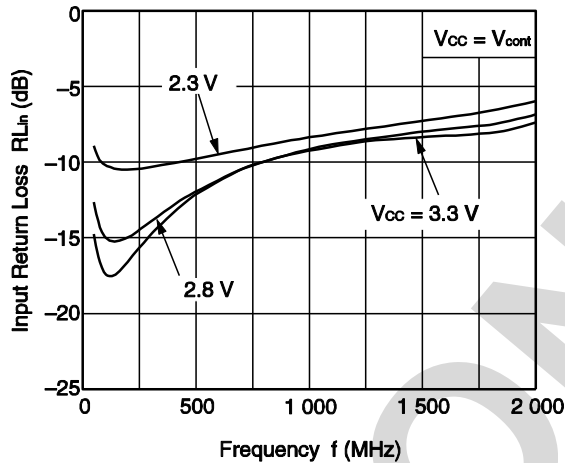
POWER GAIN vs. SUPPLY VOLTAGE



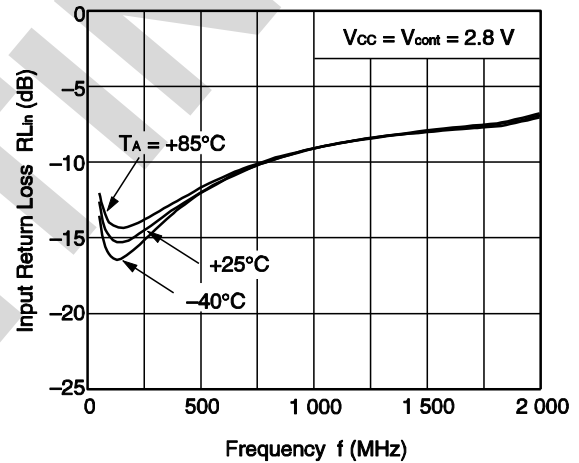
POWER GAIN vs. OPERATING AMBIENT TEMPERATURE



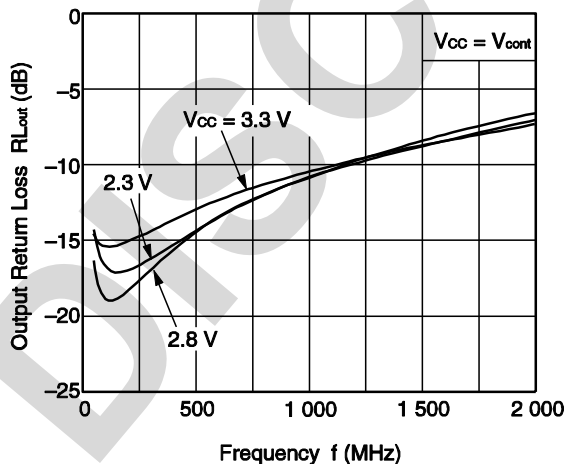
INPUT RETURN LOSS vs. FREQUENCY



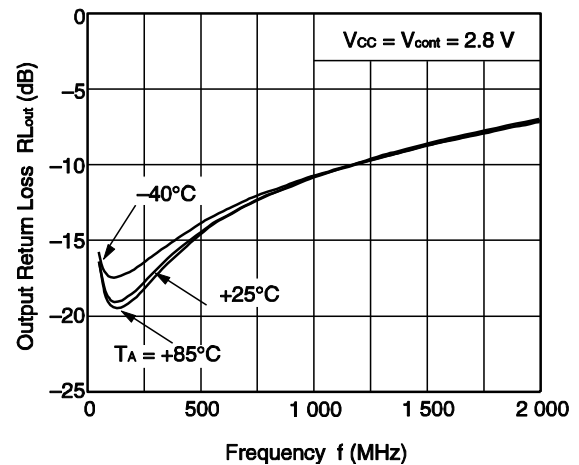
INPUT RETURN LOSS vs. FREQUENCY



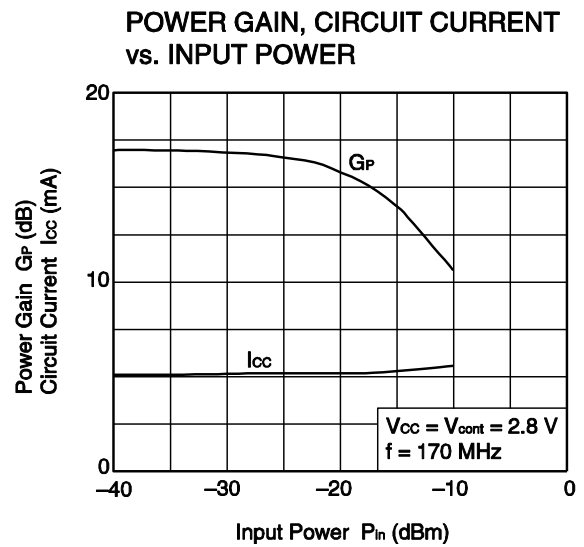
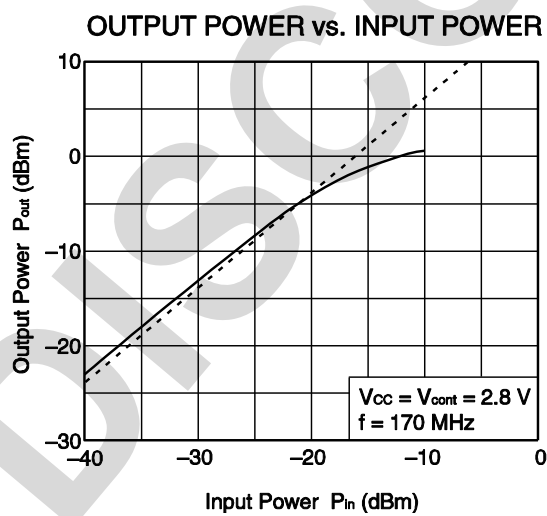
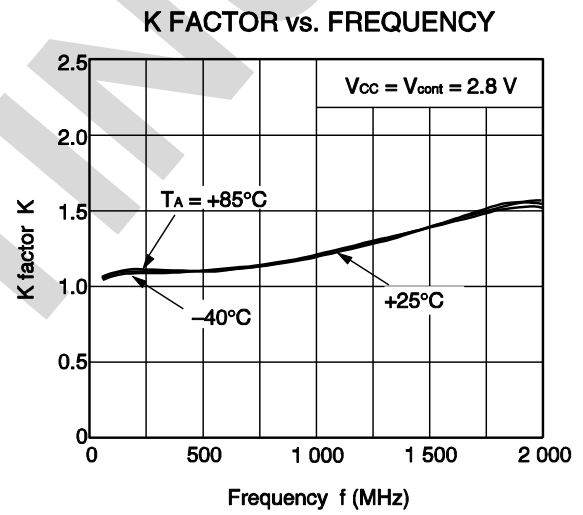
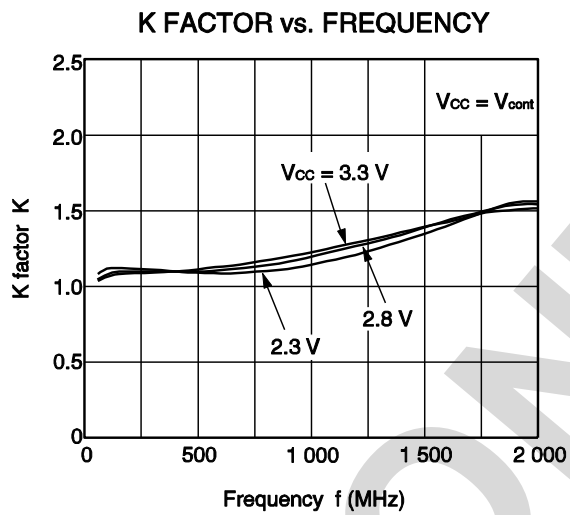
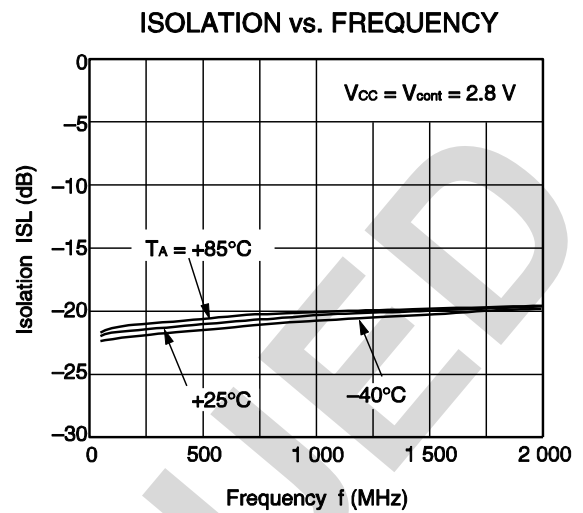
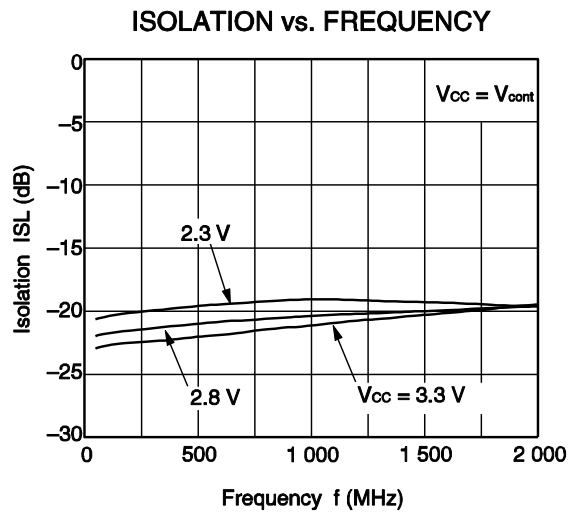
OUTPUT RETURN LOSS vs. FREQUENCY



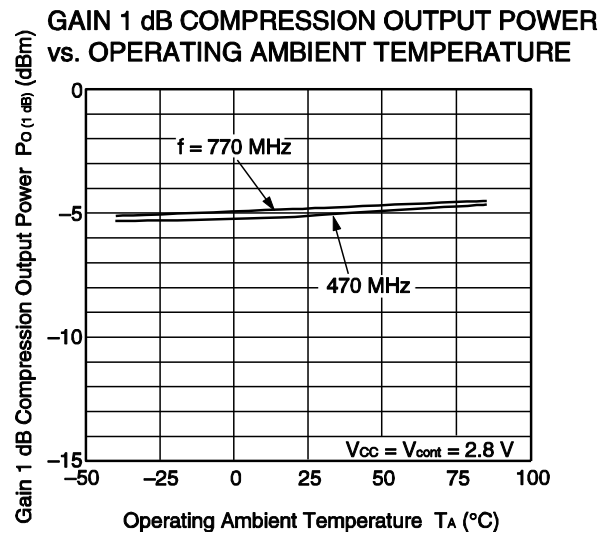
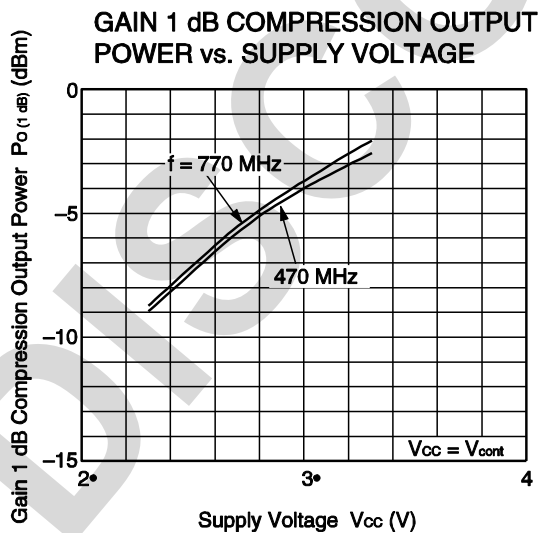
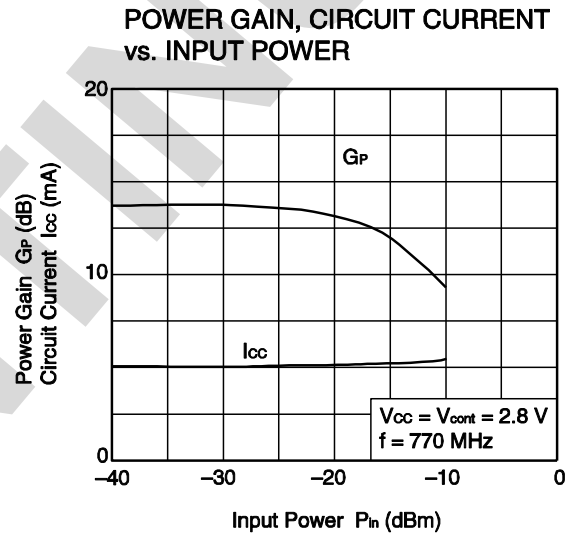
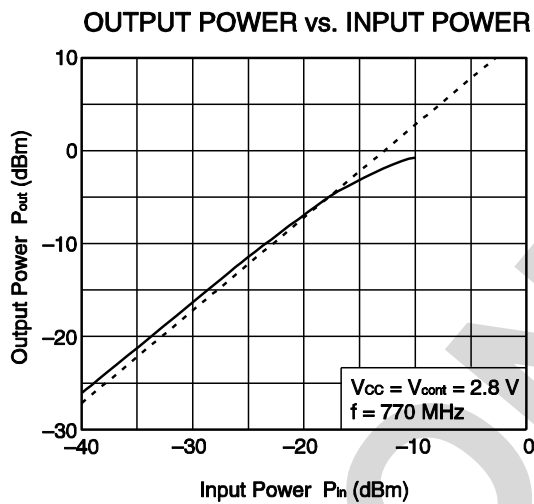
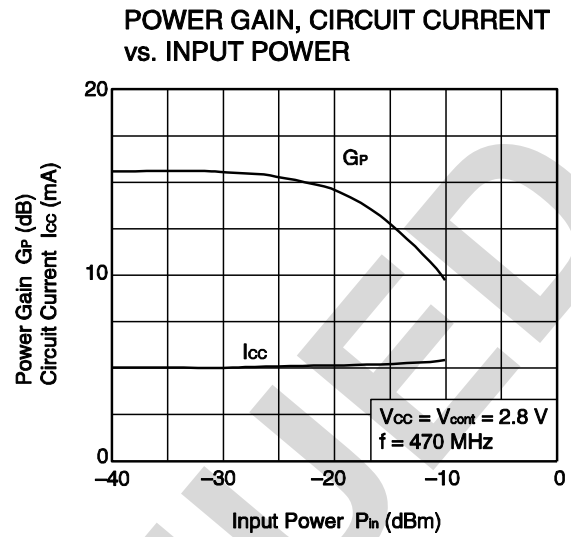
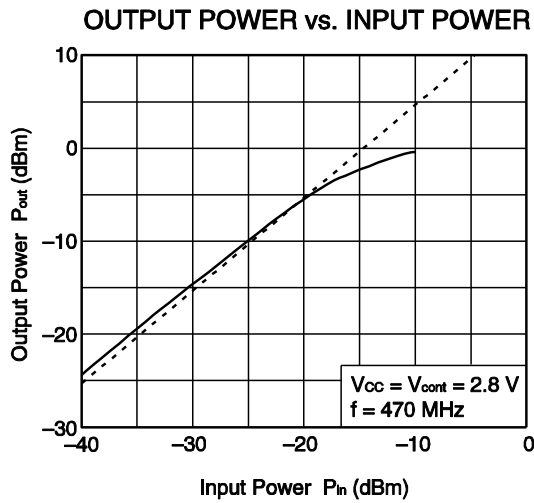
OUTPUT RETURN LOSS vs. FREQUENCY



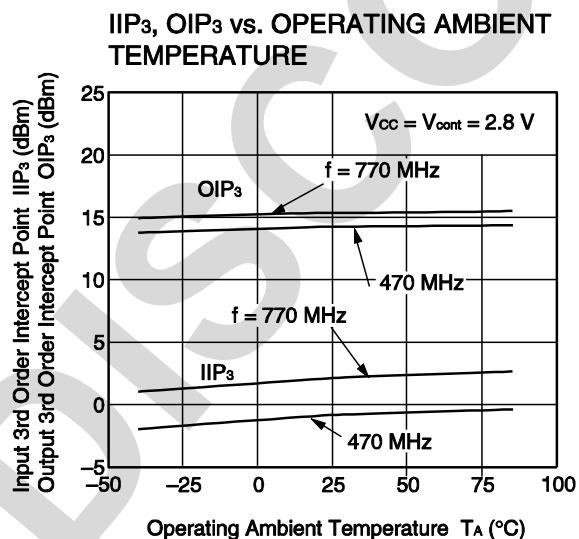
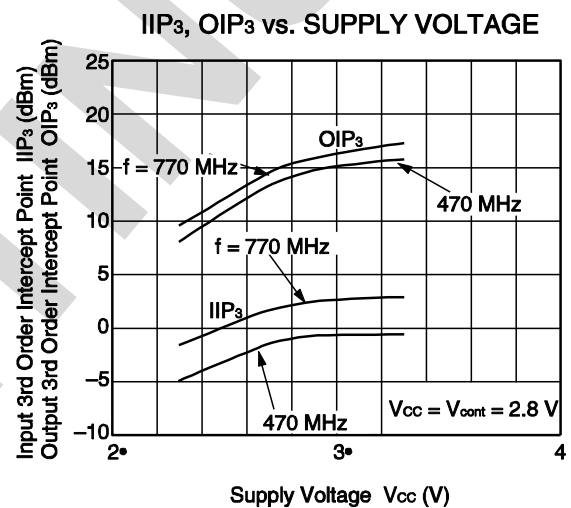
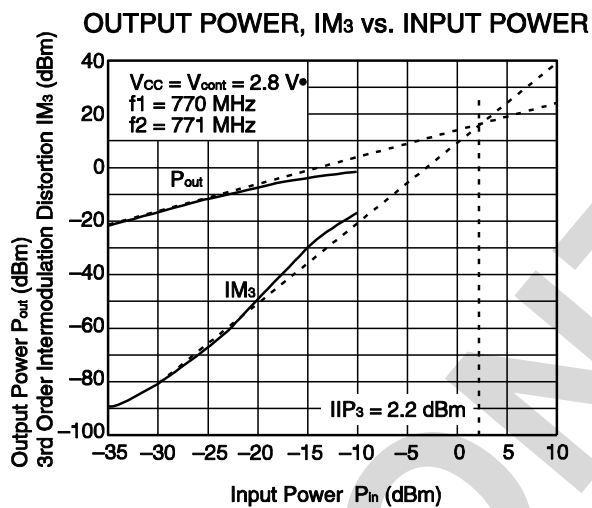
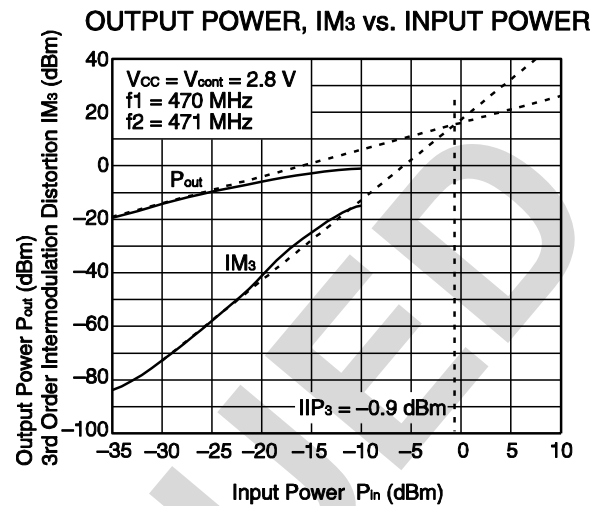
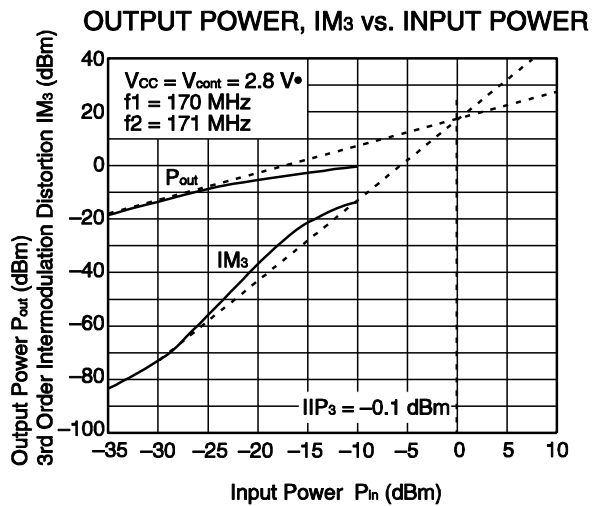
Remark The graphs indicate nominal characteristics.



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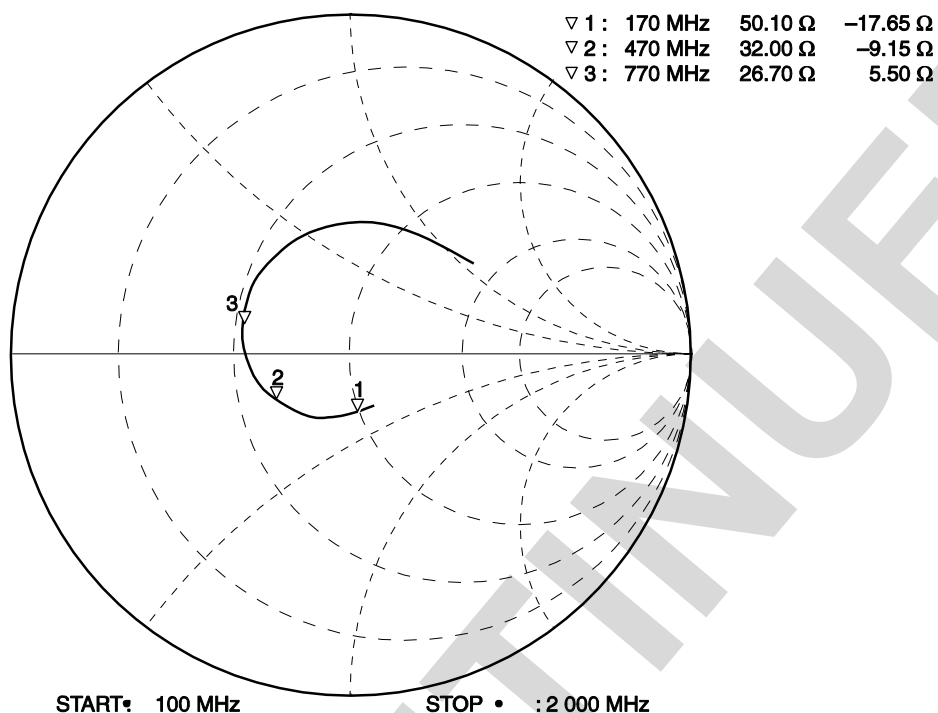
Remark The graphs indicate nominal characteristics.



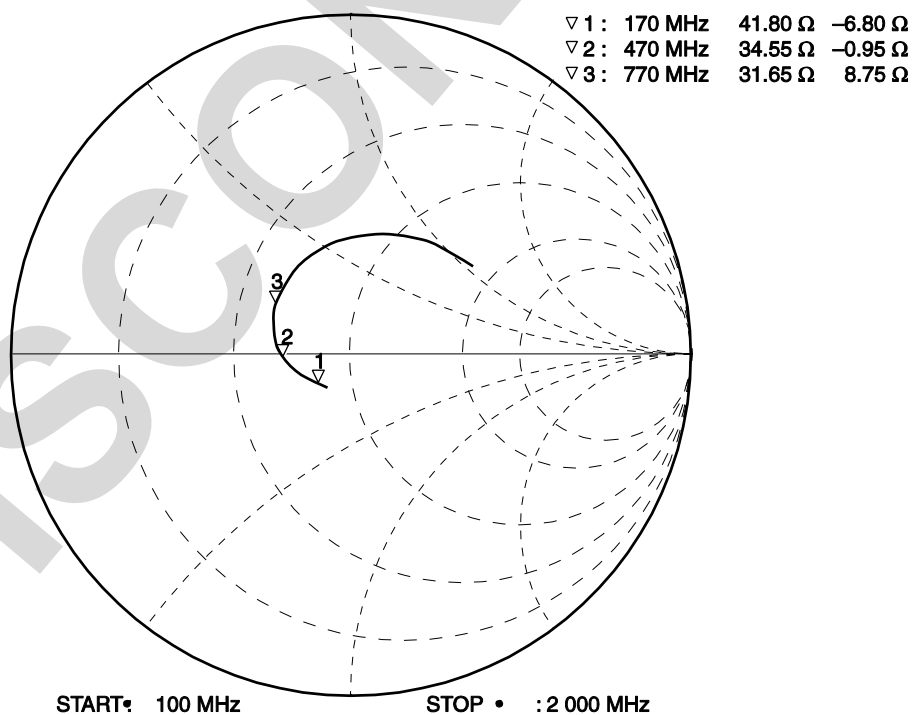
Remark The graphs indicate nominal characteristics.

S-PARAMETERS 1 (LNA-mode) ($T_A = +25^\circ\text{C}$, $V_{CC} = V_{cont} = 2.8\text{ V}$, monitored at connector on board)

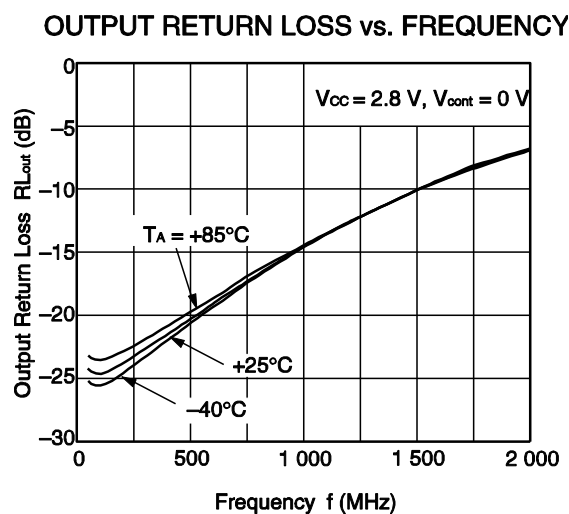
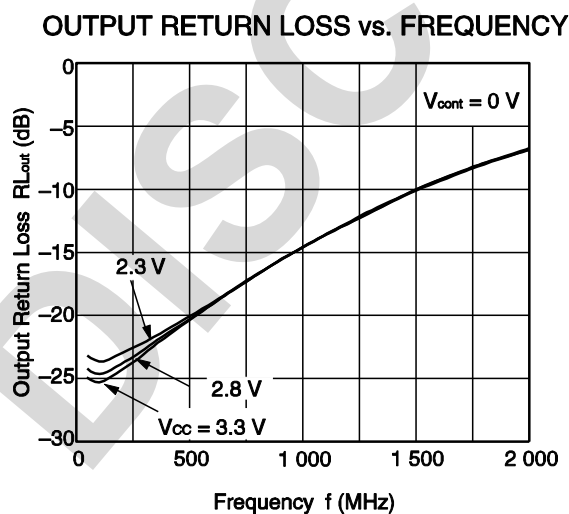
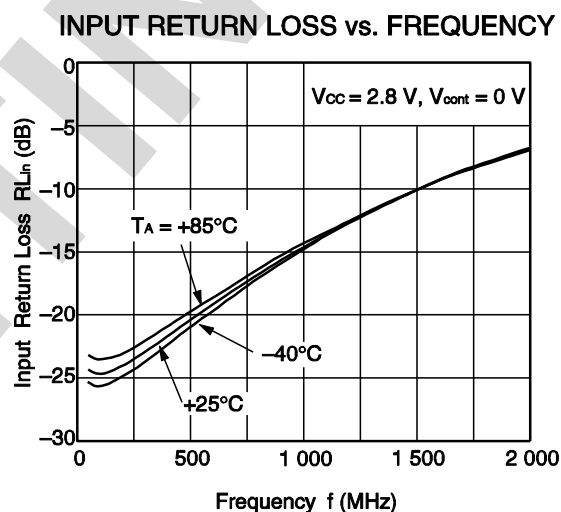
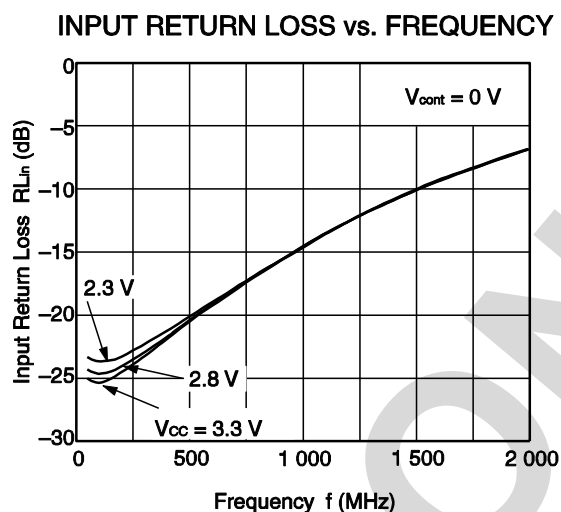
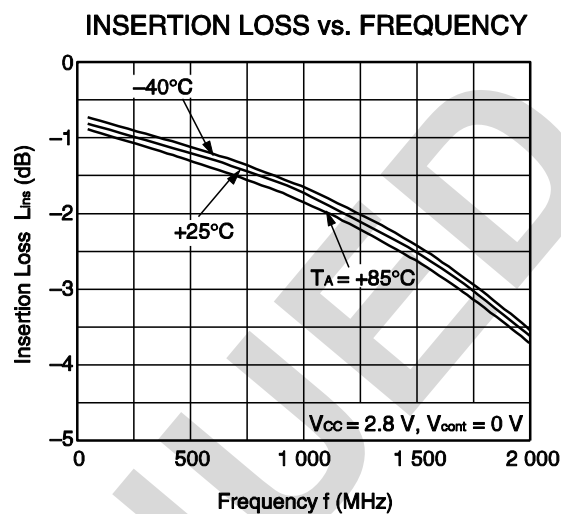
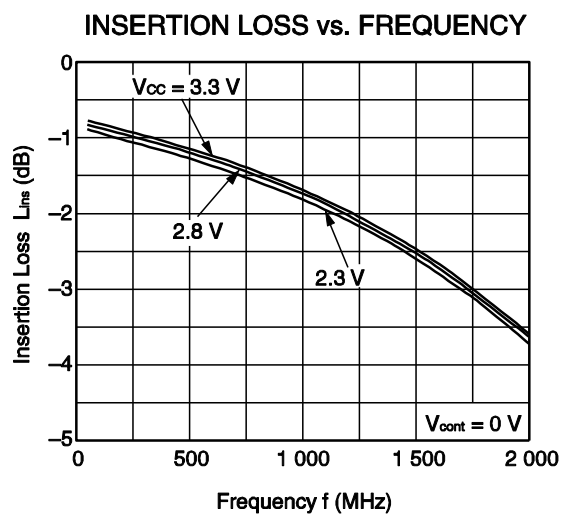
S₁₁-FREQUENCY



S₂₂-FREQUENCY

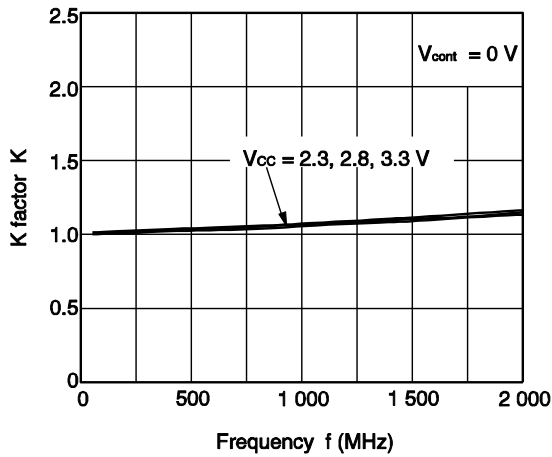


Remark The graphs indicate nominal characteristics.

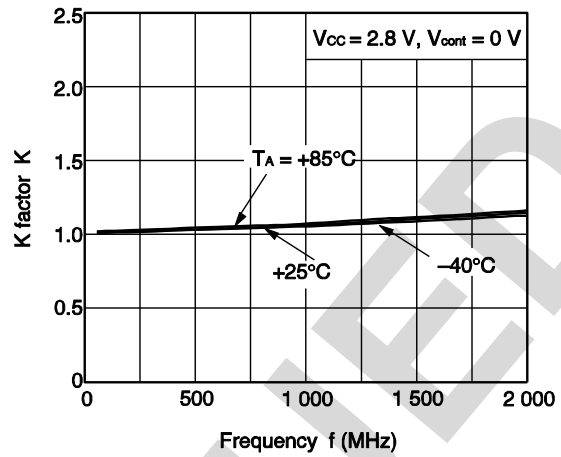
TYPICAL CHARACTERISTICS 3 (Bypass-mode) ($T_A = +25^\circ\text{C}$, unless otherwise specified)

Remark The graphs indicate nominal characteristics.

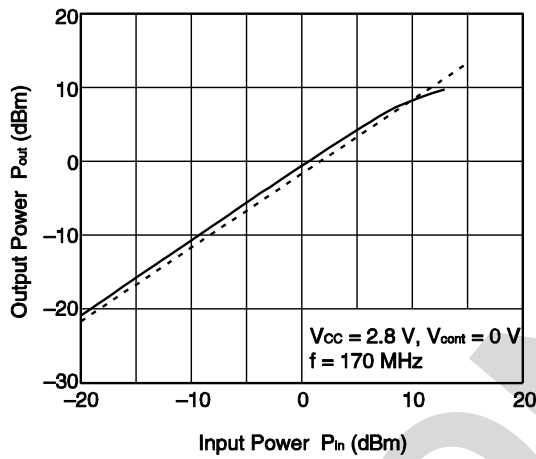
K FACTOR vs. FREQUENCY



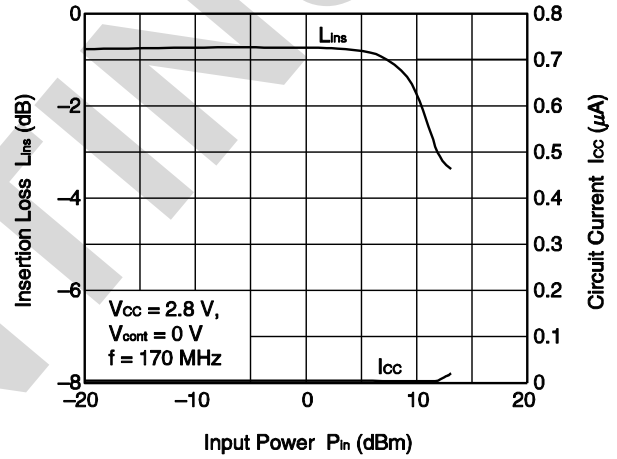
K FACTOR vs. FREQUENCY



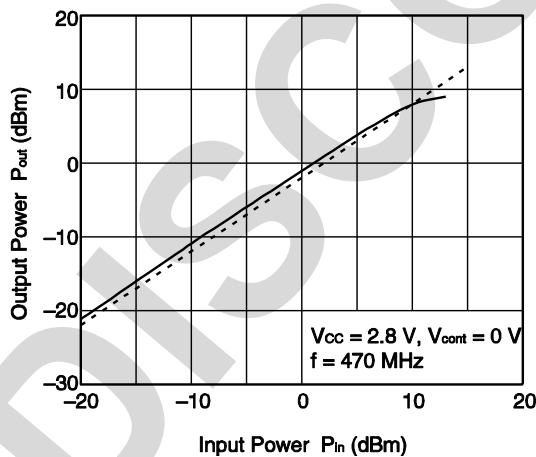
OUTPUT POWER vs. INPUT POWER



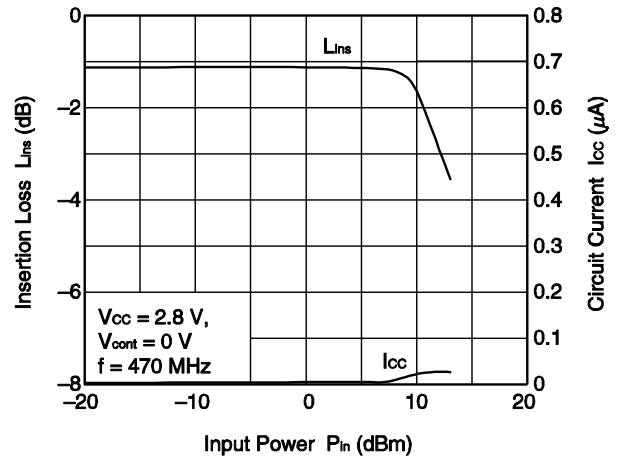
INSERTION LOSS, CIRCUIT CURRENT vs. INPUT POWER



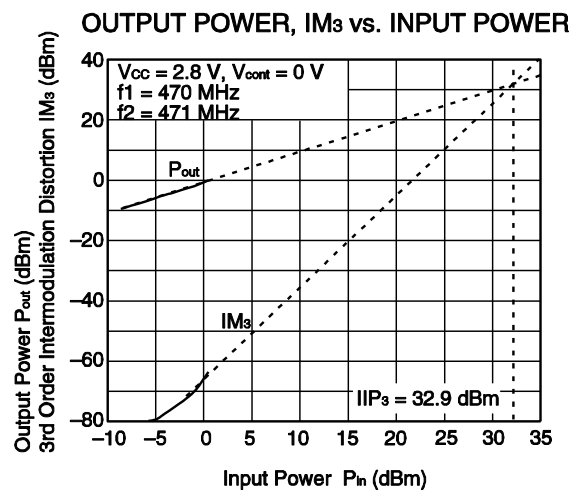
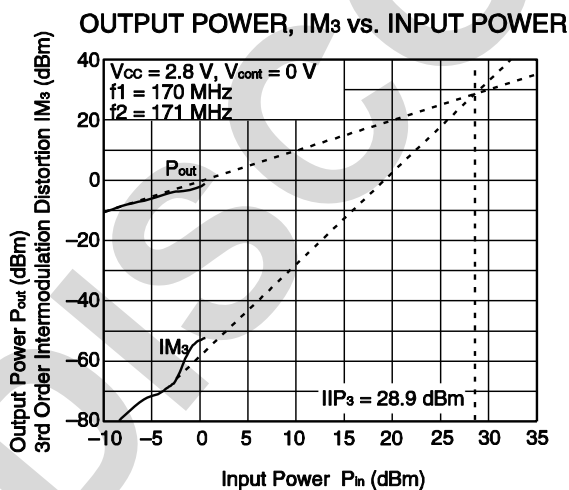
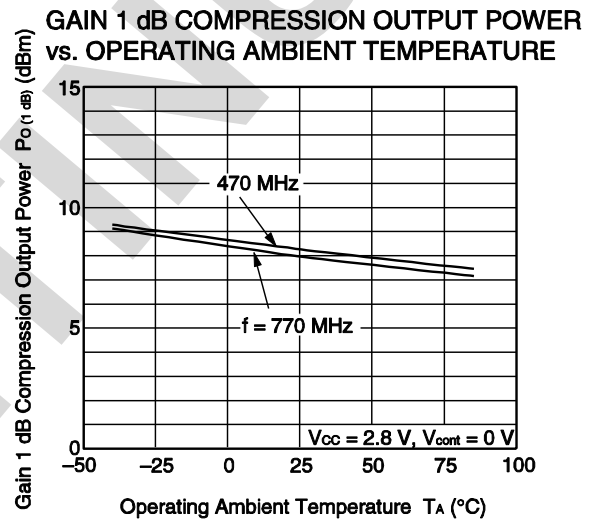
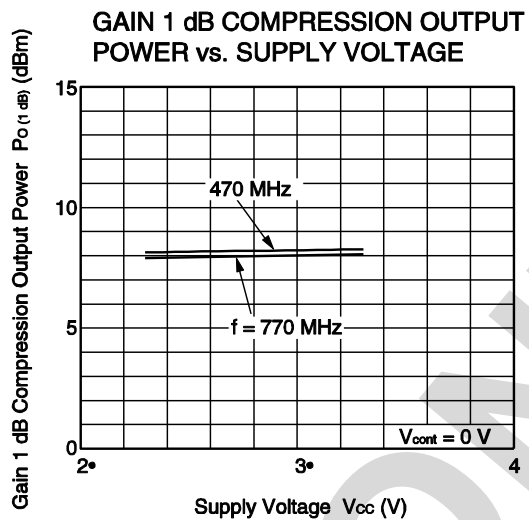
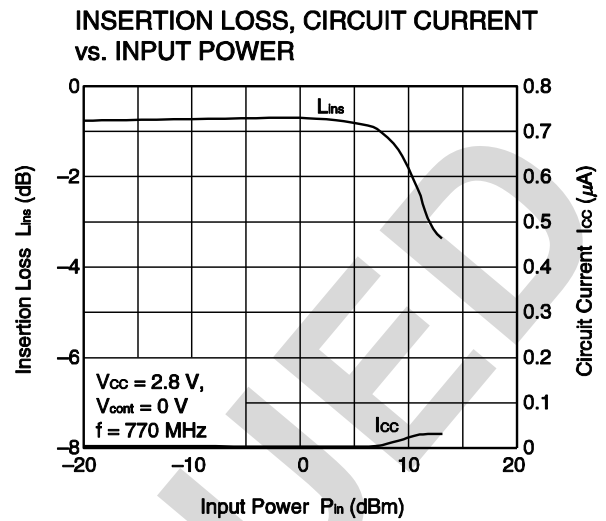
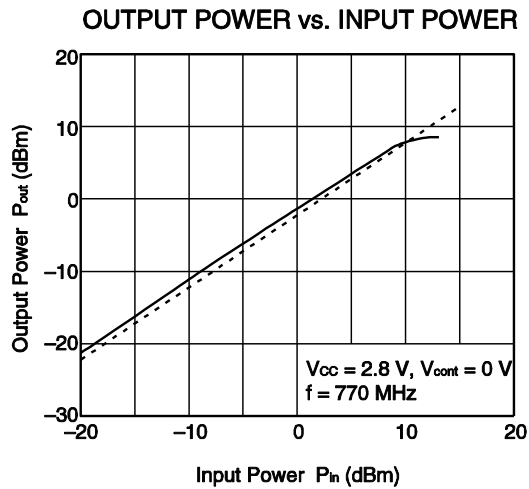
OUTPUT POWER vs. INPUT POWER



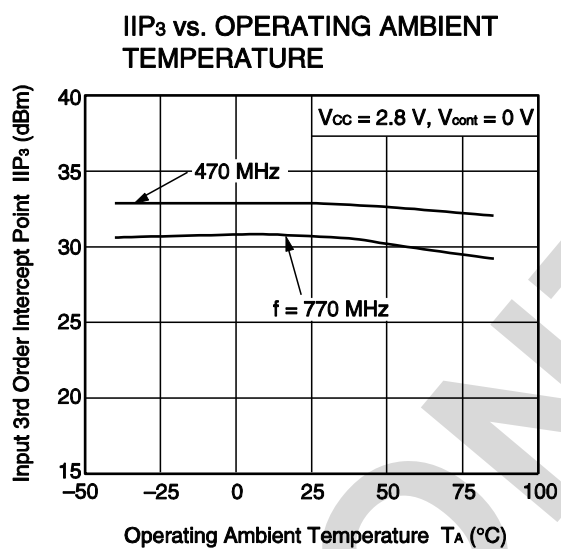
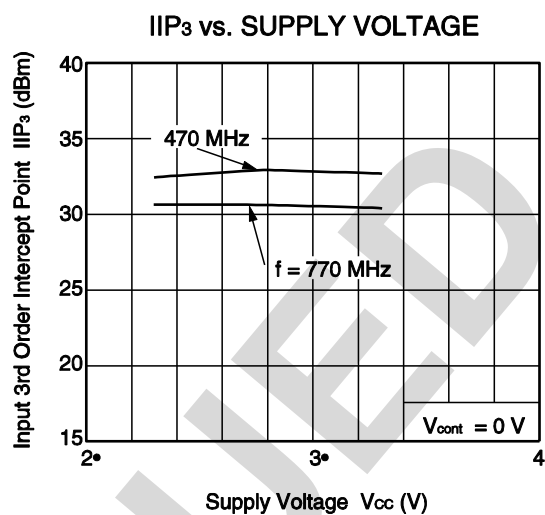
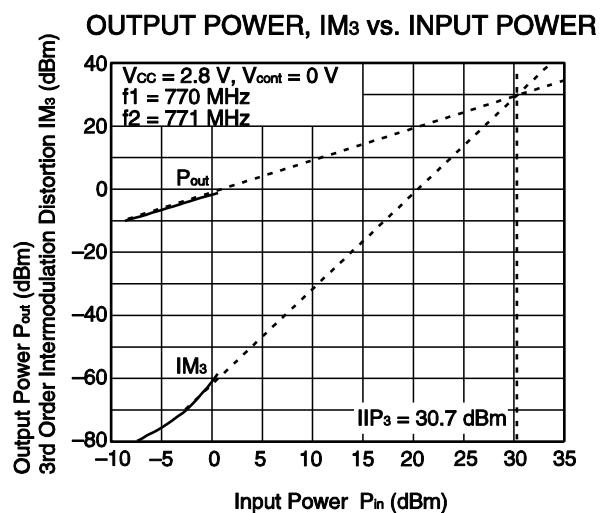
INSERTION LOSS, CIRCUIT CURRENT vs. INPUT POWER



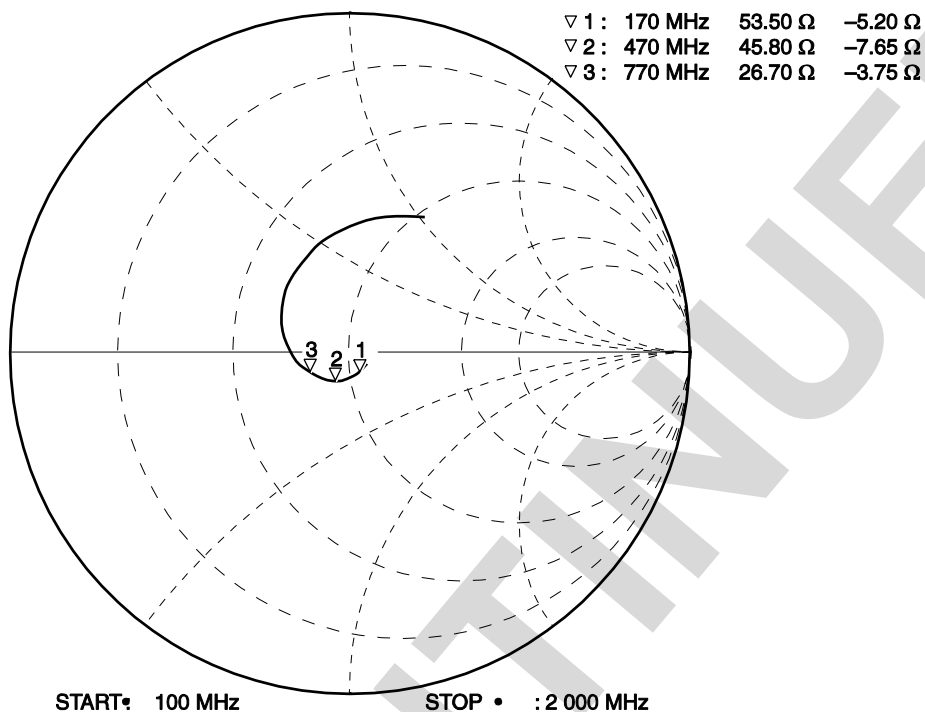
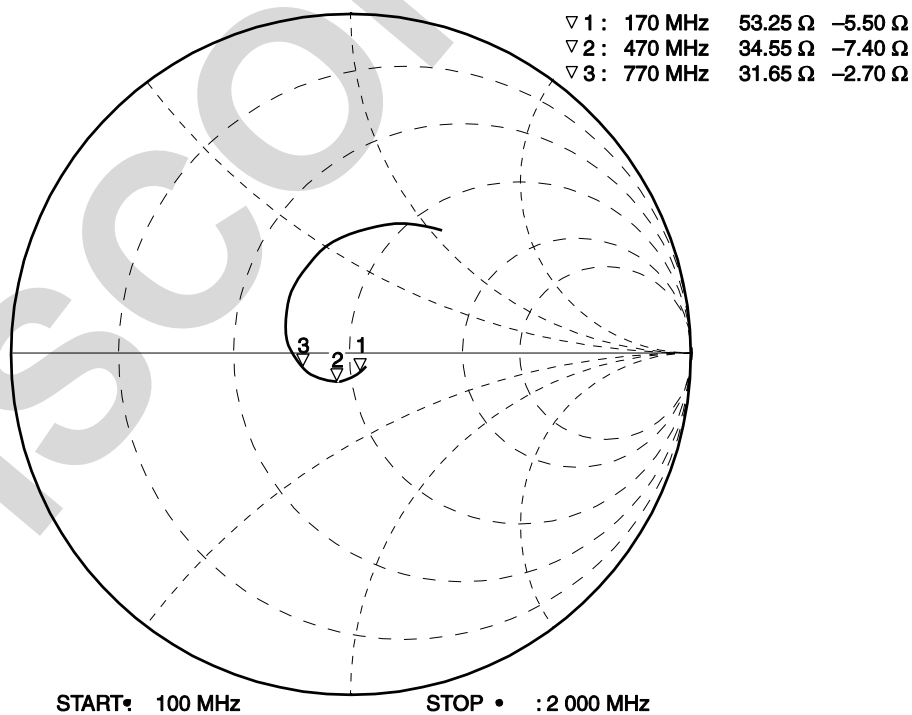
Remark The graphs indicate nominal characteristics.



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Remark The graphs indicate nominal characteristics.

S-PARAMETERS 2 (Bypass-mode)(T_A = +25°C, V_{CC} = 2.8 V, V_{cont} = 0 V, monitored at connector on board)**S₁₁—FREQUENCY****S₂₂—FREQUENCY****Remark** The graphs indicate nominal characteristics.

NOTES ON CORRECT USE

- (1) Observe precautions for handling because of electro-static sensitive devices.
- (2) Form a ground pattern as widely as possible to minimize ground impedance (to prevent undesired oscillation).
All the ground terminals must be connected together with wide ground pattern to decrease impedance difference.
- (3) The bypass capacitor should be attached to V_{cc} line.
- (4) Do not supply DC voltage to INPUT pin.
- (5) Pin 5 (NC) should be connected to the ground pattern.

RECOMMENDED SOLDERING CONDITIONS

This product should be soldered and mounted under the following recommended conditions. For soldering methods and conditions other than those recommended below, contact your nearby sales office.

Soldering Method	Soldering Conditions	Condition Symbol
Infrared Reflow	Peak temperature (package surface temperature) : 260°C or below Time at peak temperature : 10 seconds or less Time at temperature of 220°C or higher : 60 seconds or less Preheating time at 120 to 180°C : 120±30 seconds Maximum number of reflow processes : 3 times Maximum chlorine content of rosin flux (% mass) : 0.2%(Wt.) or below	IR260
Partial Heating	Peak temperature (terminal temperature) : 350°C or below Soldering time (per side of device) : 3 seconds or less Maximum chlorine content of rosin flux (% mass) : 0.2%(Wt.) or below	HS350

Caution Do not use different soldering methods together (except for partial heating).